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Développement de détecteurs Micromegas pixellisés pour l'expérience COMPASS

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COMPASS et les détecteurs Micromegas

Le projet

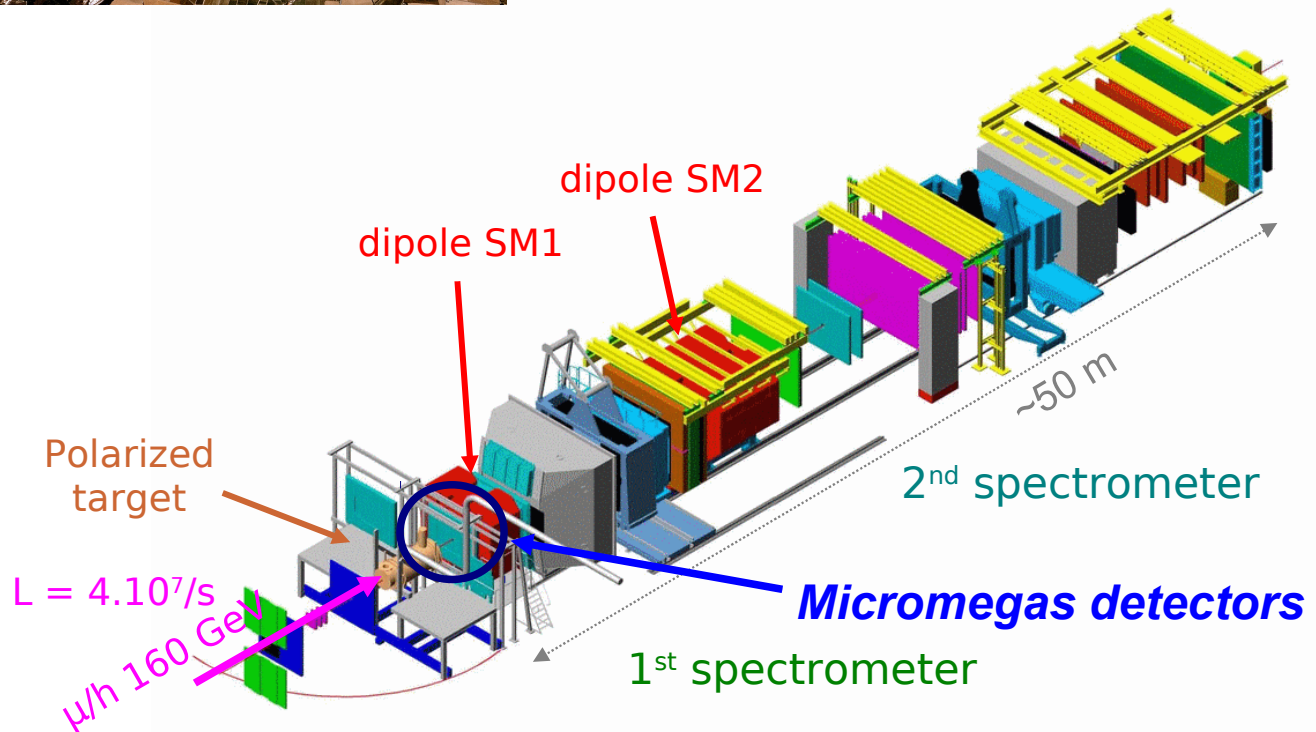
Les prototypes pixellisés

La réduction de l'impact des décharges

The COMPASS experiment at CERN



Dedicated to nucleon structure and spectroscopy studies
2 spectrometers for small and large angles
High statistic experiment (30kHz trigger rate)
Very good spatial resolution (<100 μ m) required for kinematics and particle identification



Present COMPASS Micromegas detectors

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Interest of Micromegas

Ions neutralized by mesh

Short signals → high flux

Main characteristics

Large size 40x40 cm² with deported electronics

Reduced discharge rate with light gas and low noise electronics

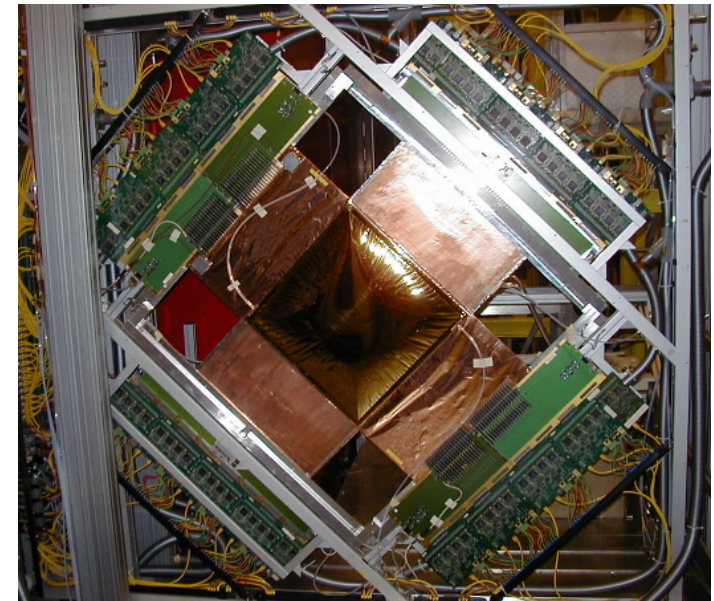
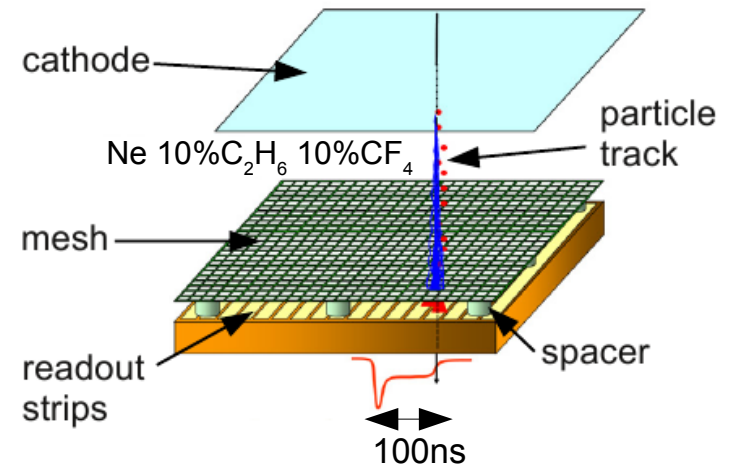
Very good performances (70-100μm, 10ns resolution)

Room for improvements

Blind center (5cm diameter disk in amplification gap, beam area)

Discharge rate in amplification gap is limiting factor with hadron beam

Micro-Mesh Gaseous Detectors



New MM R&D project

New proposal discussed in COMPASS collaboration for several years

→ Opportunity for the evolution of the MM detectors

Main objectives of the project

Detectors active in beam area

Less discharge → stand 5 times higher flux hadron beams

New MM detector to design with:

10 to 100 times less discharges

Read-out with pixels in the detector center (beam area)

Integrated electronics (APV25 chips)

Robustness improved (bulk technology)

Pixels read-out in the detector center

Too high flux for strips

Expected particle flux > 100kHz/mm²

→ > 500kHz/channel if strip read-out

→ > 10% inefficiency !

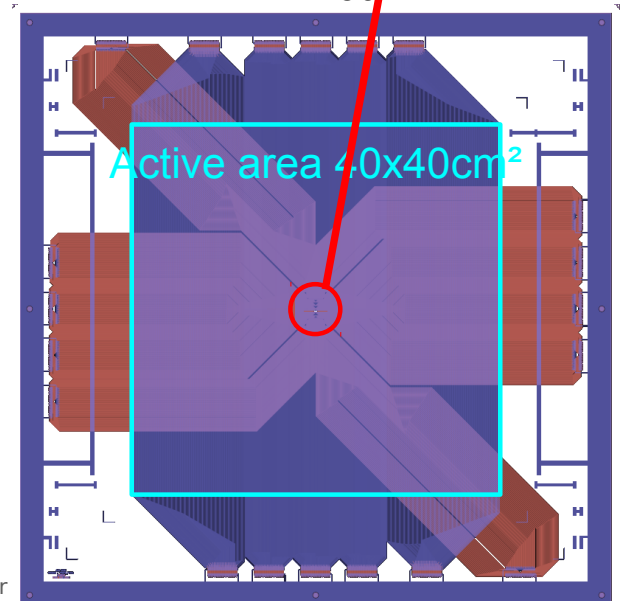
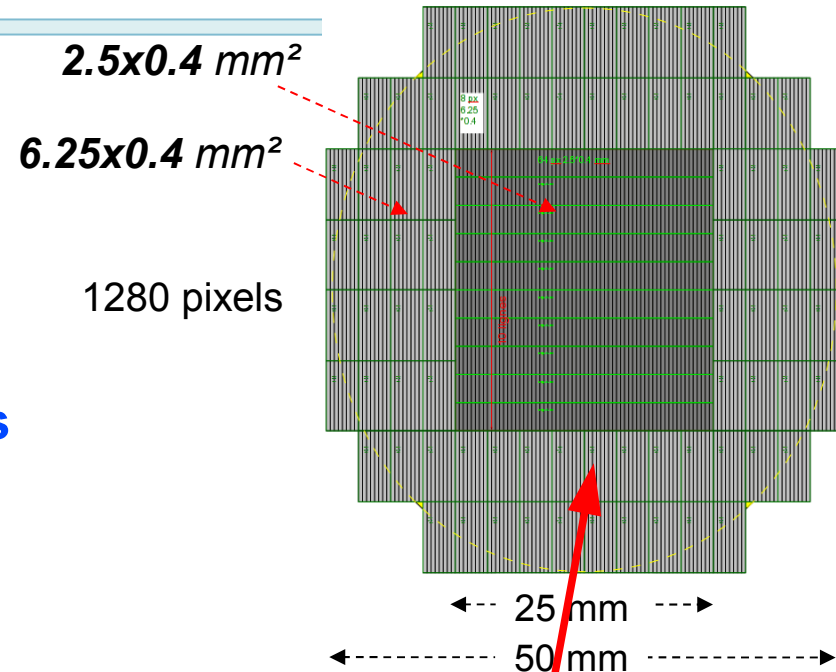
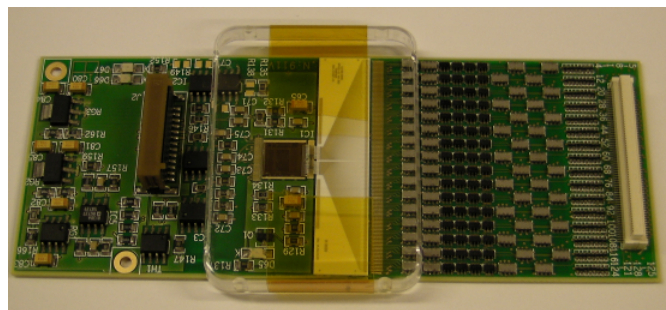
Read-out with rectangular pixels

5cm diameter, cover present inactive area

Keep spatial resolution in perpendicular dimension (400μm pitch as strips)

1280 pixels + 1280 strips to read !

Read-out electronics: 128-channels APV25 chips (from CMS silicon detectors, card design derived from TUM Munich)



Active area 40x40cm²

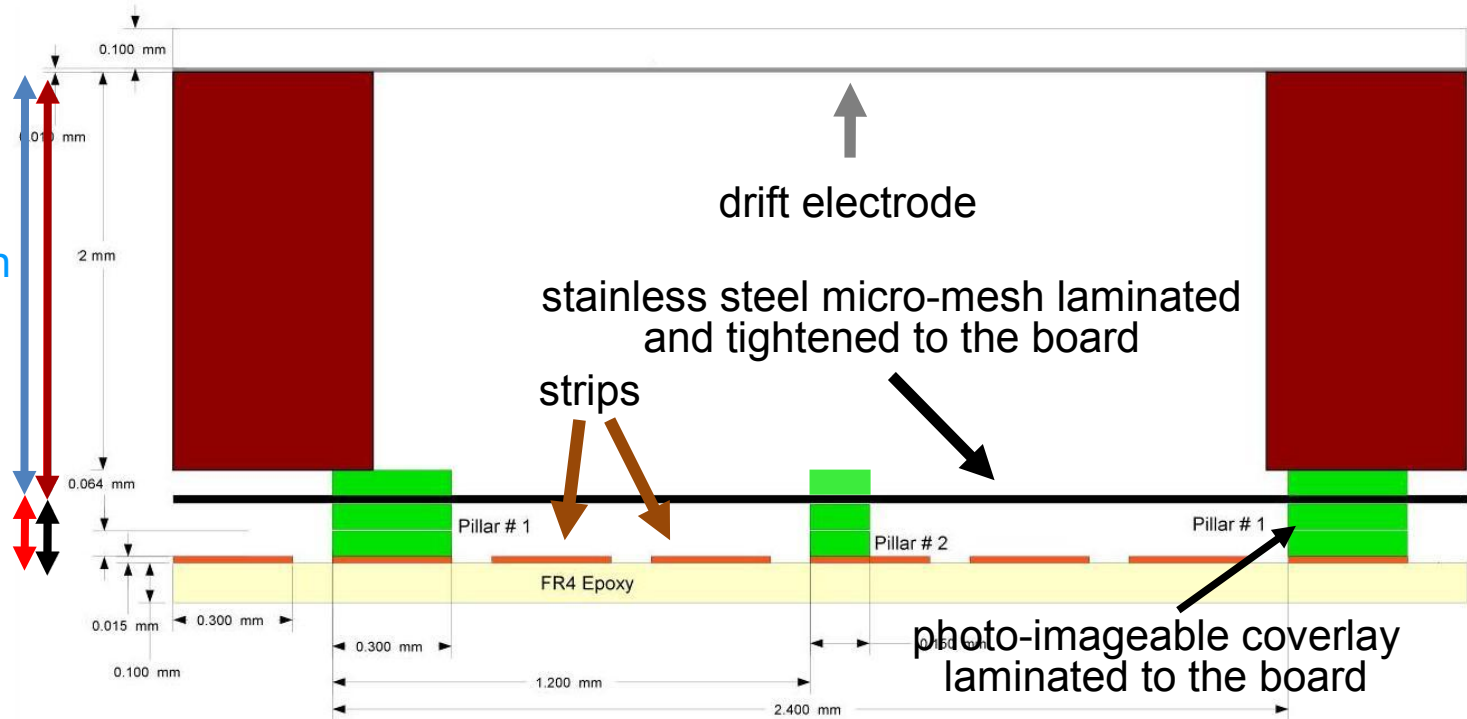
Improved robustness with bulk technology

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amplification



Developed at Saclay and Cern, can be produced at Cern lab

Advantages:

- monolithic detector → no dust beneath the mesh
- less mechanical constraint (no more frame to tight the mesh)
- R&D done to produce bulk MM on honeycomb sandwich

Works on 2009 prototypes

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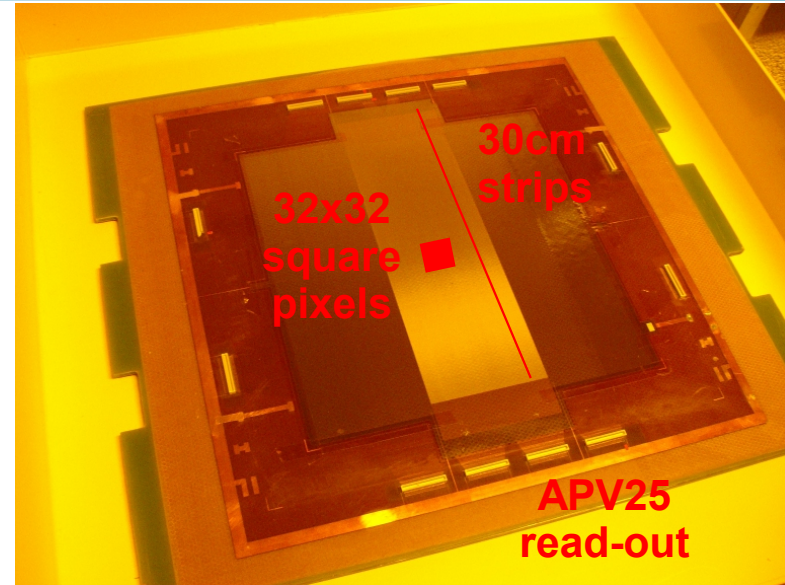
2009 prototypes

32x32 1mm² square pixels and 30cm strips (design from TUM Munich)

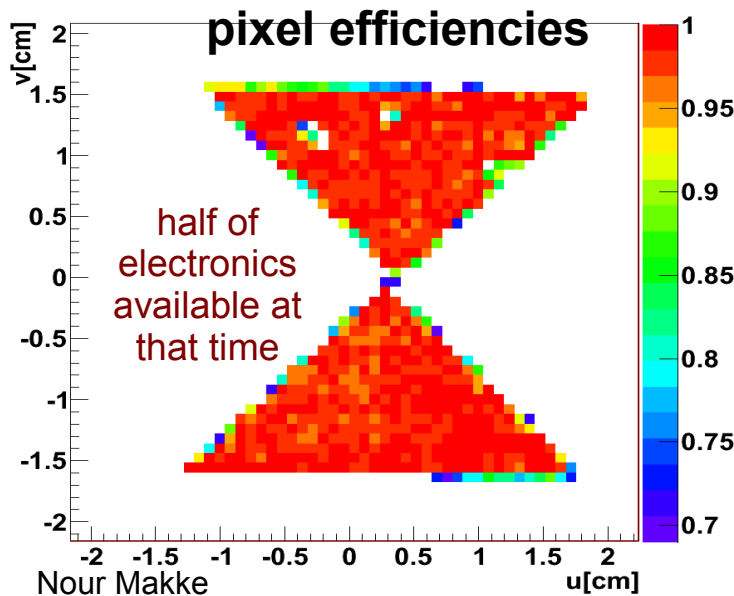
Comparison bulk/non-bulk technologies, no difference in discharge rate

Validation of APV25 read-out on Micromegas

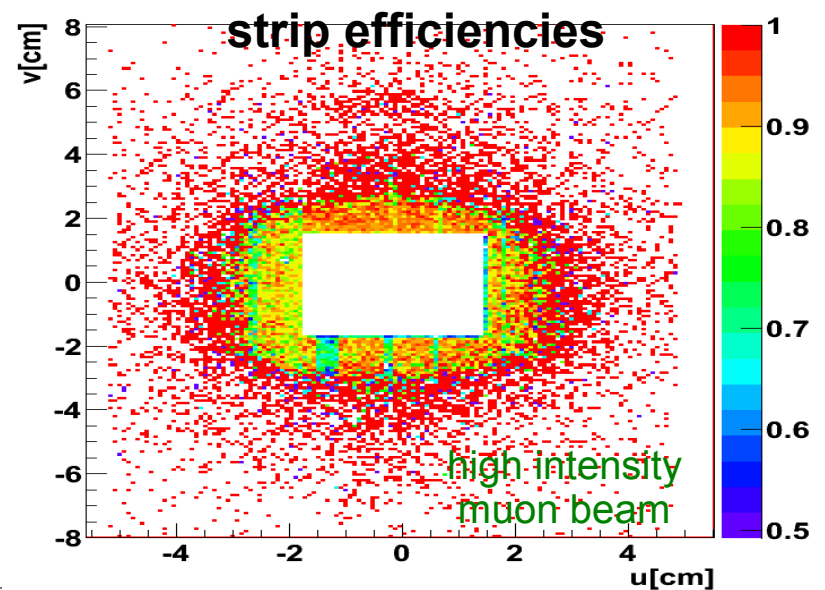
Installed in COMPASS muon and hadron beam



Efficacite



Efficacite



Works on 2010 prototype

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2010 prototype

Almost final design

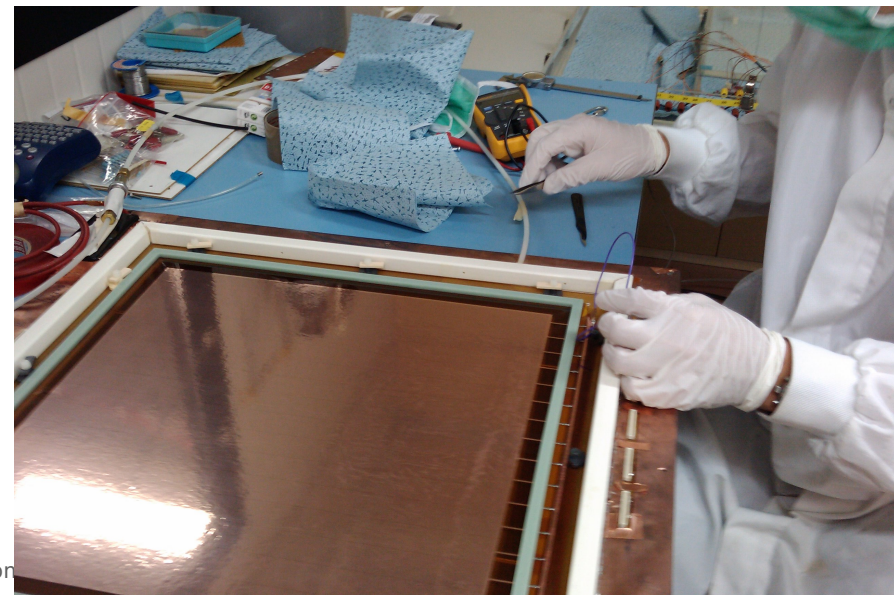
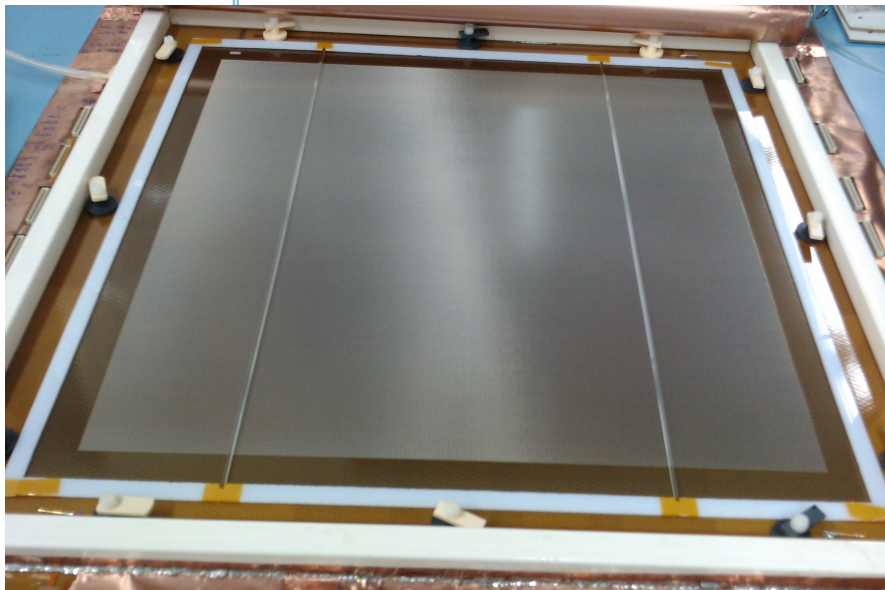
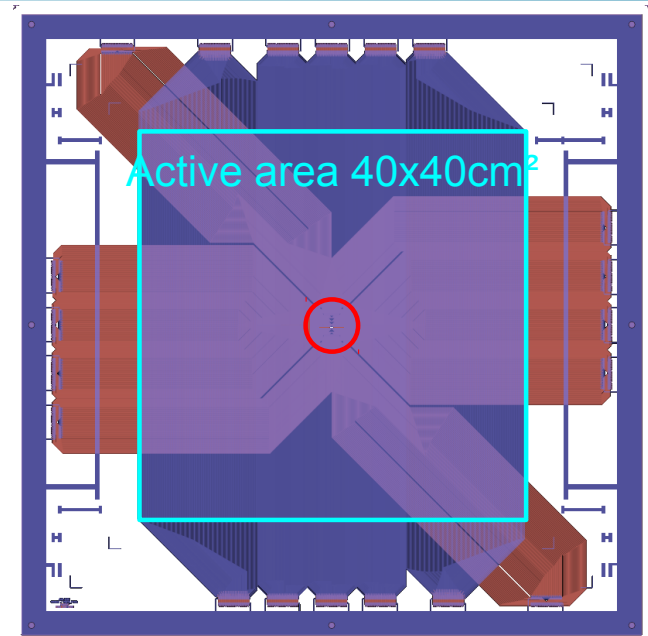
*40x40cm² active area with 1280
rectangular pixels*

Installed in COMPASS muon beam

*GEM foil added for last days of
COMPASS run*

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Résultats préliminaires sur le prototype 2010

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Zone pistes

Bonne efficacité à grand flux de muons

Zone pixels

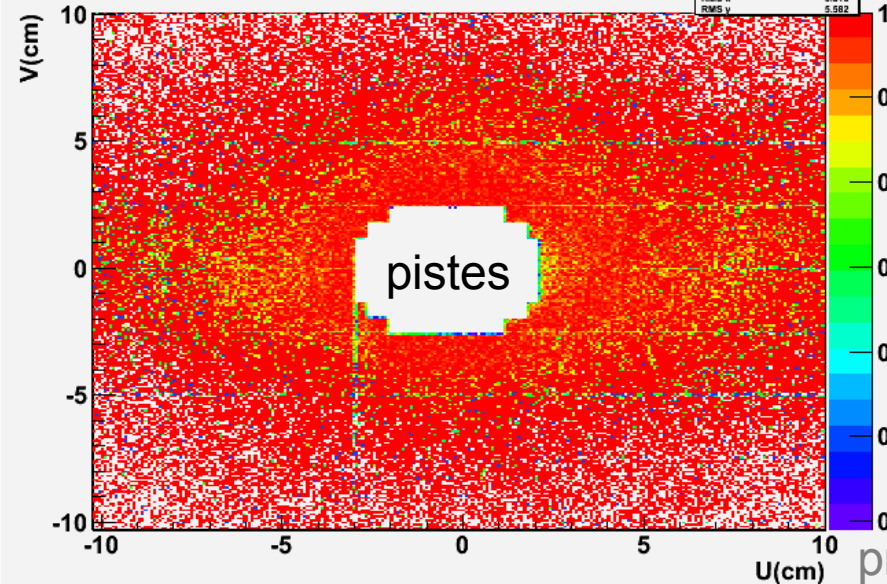
Efficacité dégradée par canaux manquants (>5%) et occupation de l'électronique (signal mis en forme >500ns)

Paramétrage de l'électronique APV (registres) à optimiser

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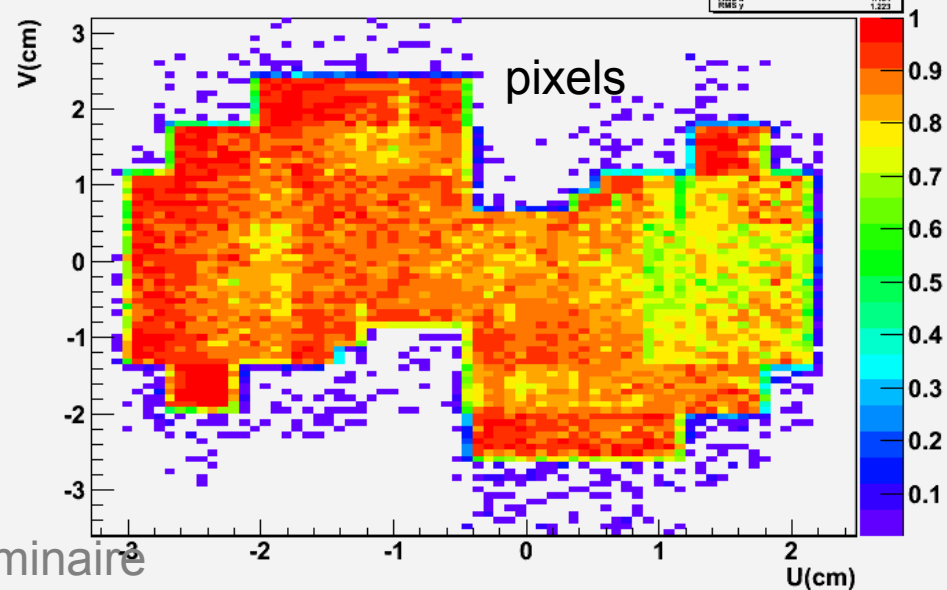
V vs U of strip efficiency with noise correction

stripdetcorref	
Entries	109246
Mean x	0.0398
Mean y	0.04701
RMS x	5.816
RMS y	5.982



V vs U of pix efficiency with noise correction

pixdetcorref	
Entries	2438
Mean x	-0.4928
Mean y	-0.09804
RMS x	1.464
RMS y	1.221



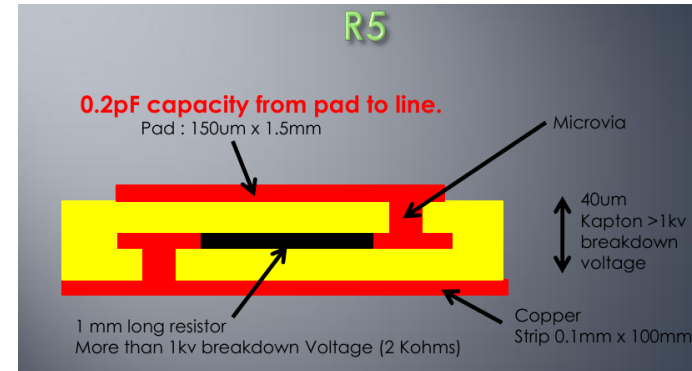
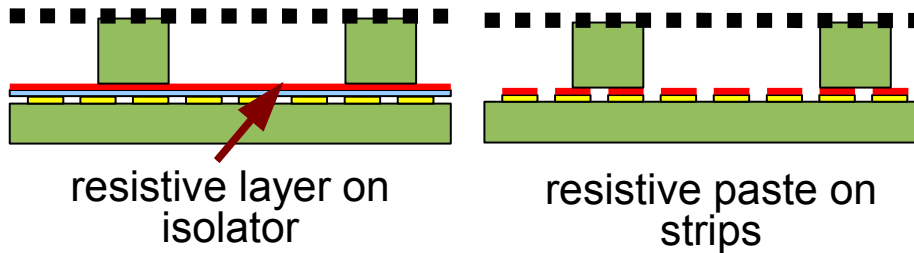
Discharge rate reduction: 2 possible ways

Resistive Micromegas

Resistive layer on top of anode to reduce discharge amplitudes

With or without isolator layer

Several evolutions ongoing in the domain

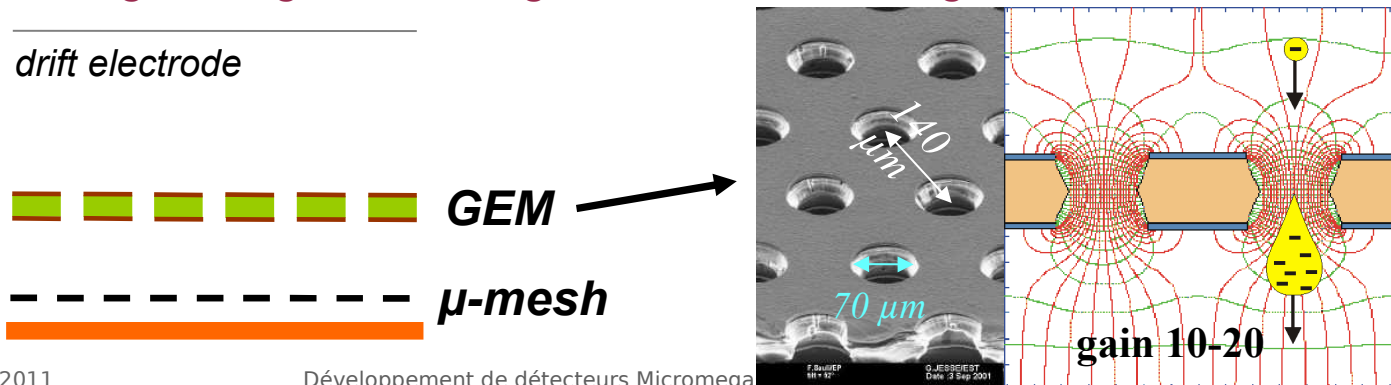


Buried resistors design of R. de Oliveira et al.

Micromegas + 1 GEM foil

Preamplification with a GEM foil (gain 10-20)

Micromegas stage at lower gain → less discharge



Beam tests on small prototypes for discharge and performances studies

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Common studies with Saclay Jefferson lab CLAS12 group

Both solutions studied

10x10cm² MM boards with 400 μ m pitch strips

Several types of resistive detectors (including last design with buried resistors from R. de Oliveira et al.)

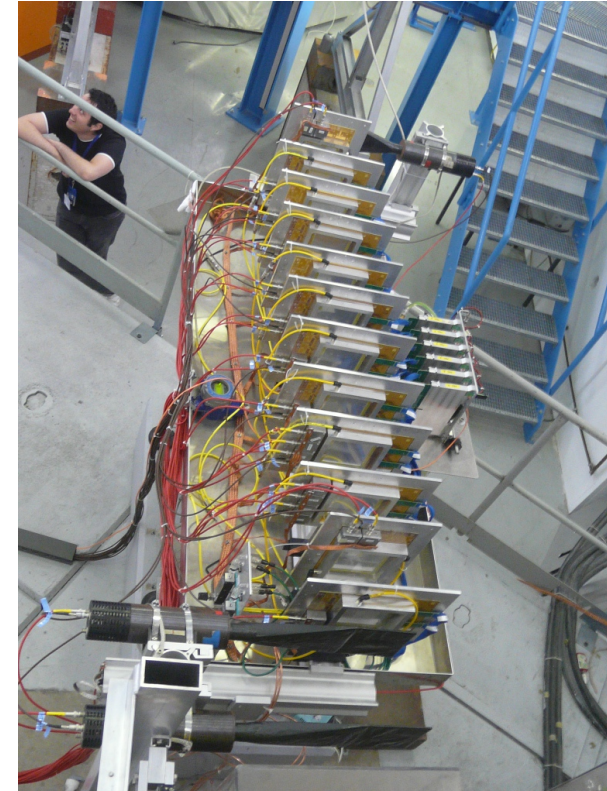
Prototypes featuring a GEM foil

Tests with different conditions

High flux 150 GeV hadron beam at CERN SPS (2009, 2010) in framework of RD51 collaboration

High flux 150 GeV muon beam (2009, 2010) for performance measurements

Low energy (0.3-3 GeV) hadron beam at PS (2010)

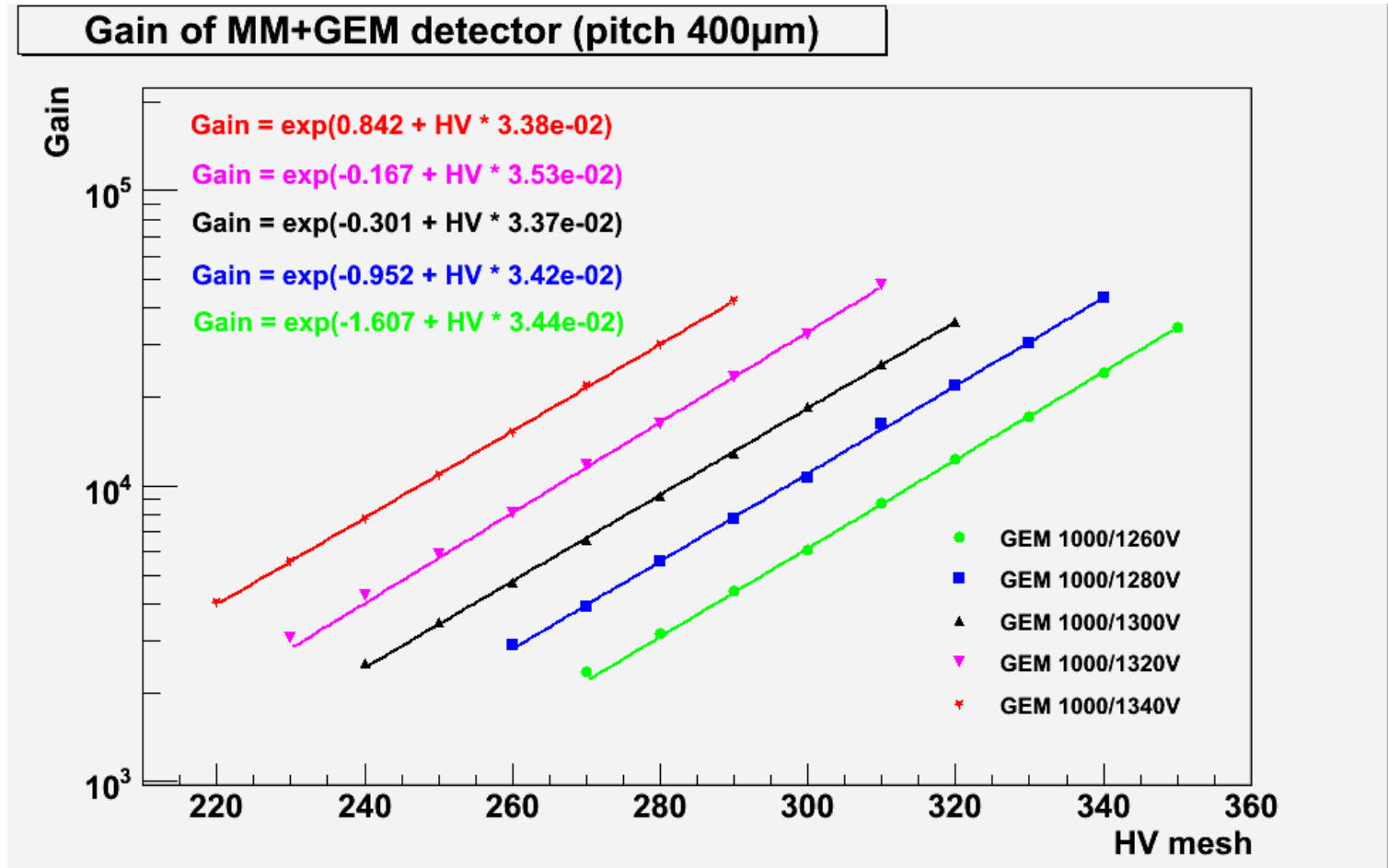


Gain of “MM+GEM” detector

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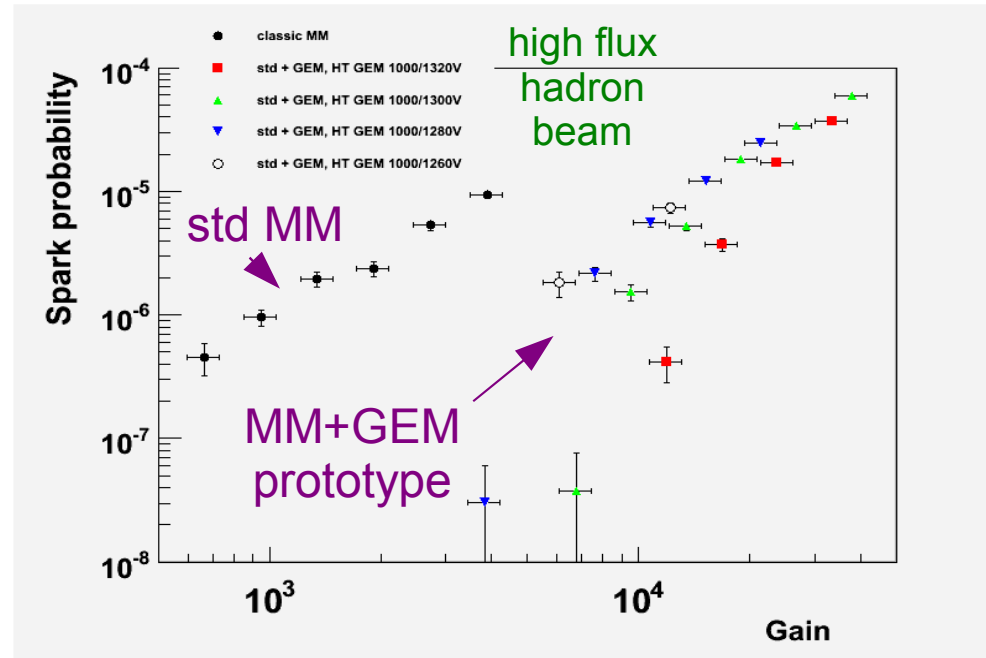
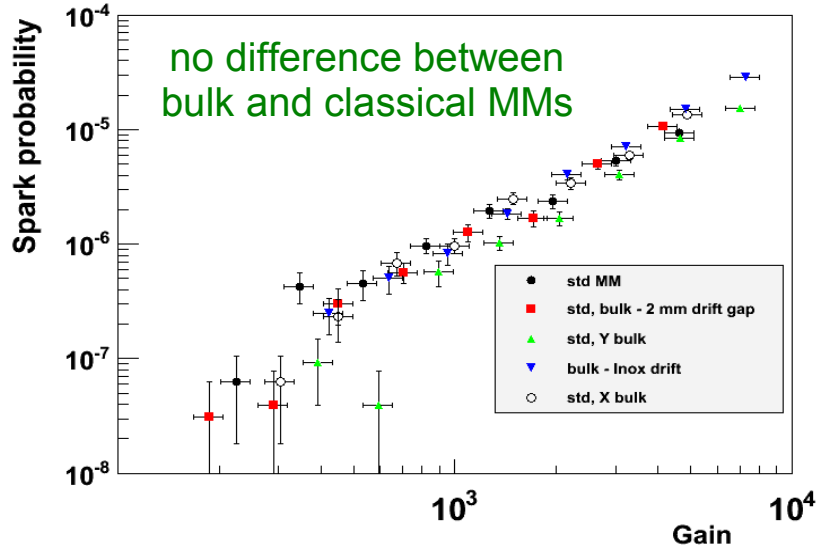


2 parameters only: HT mesh and HT top GEM
Gain detector = gain MM * gain GEM

Spark probability of MM+GEM (2009 tests)

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Rate reduced by 10 to 100 with MM+GEM prototype compared to standard Micromegas

Spark probability of MM+GEM (2010 PS tests)

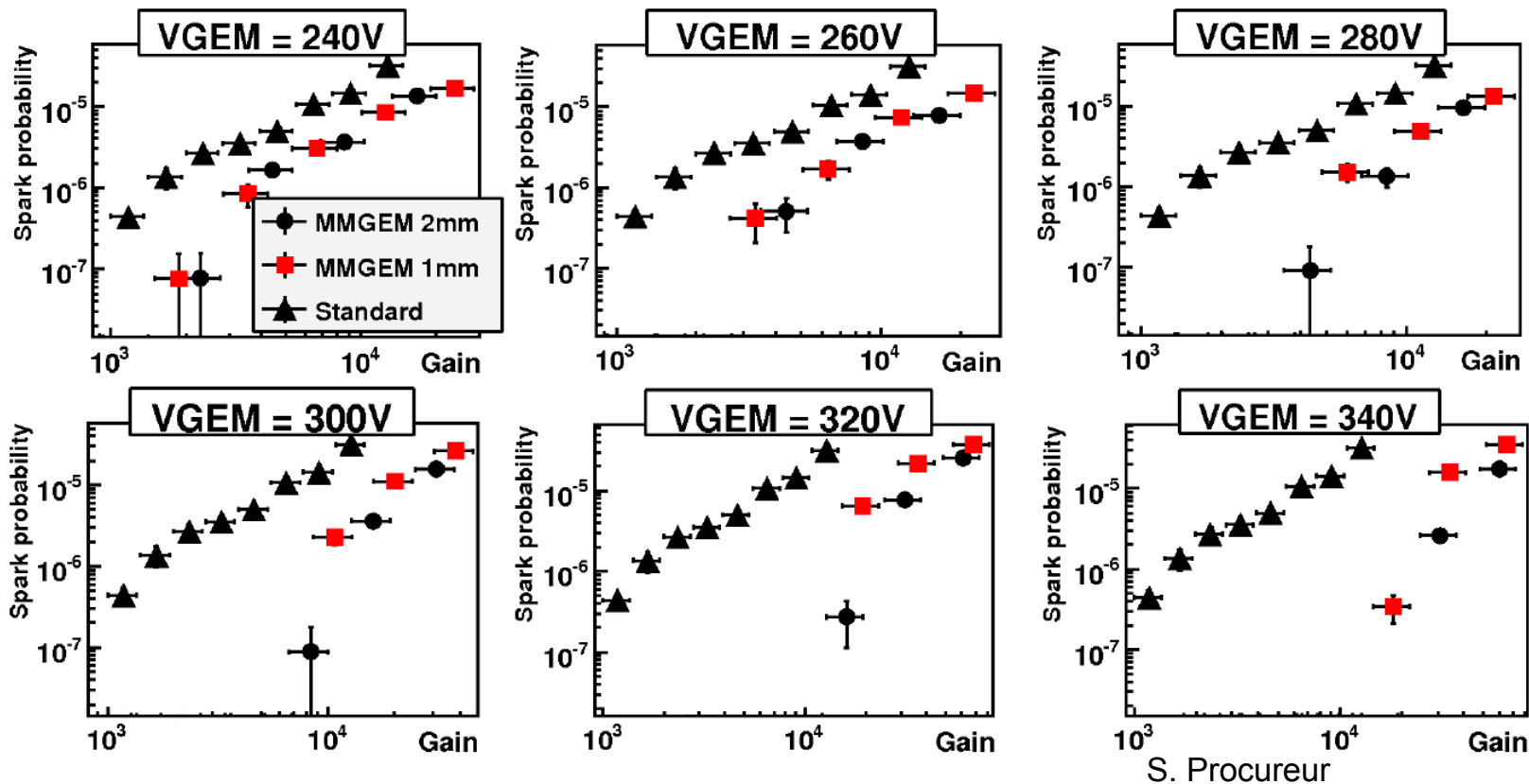
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2 MM+GEM prototypes

1 and 2mm distance between mesh and GEM foil



2 effects which explain discharge rate reduction:

- lower gain on mesh stage (charges deposited between GEM and mesh)
- charge dispersion between GEM and mesh (charges before GEM)

Efficiencies and cluster sizes vs gain (2009 tests)

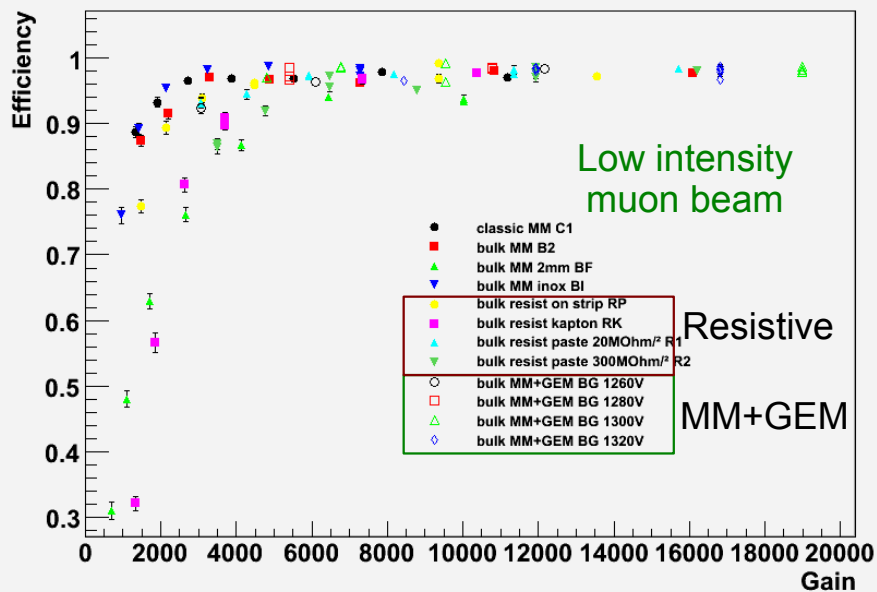
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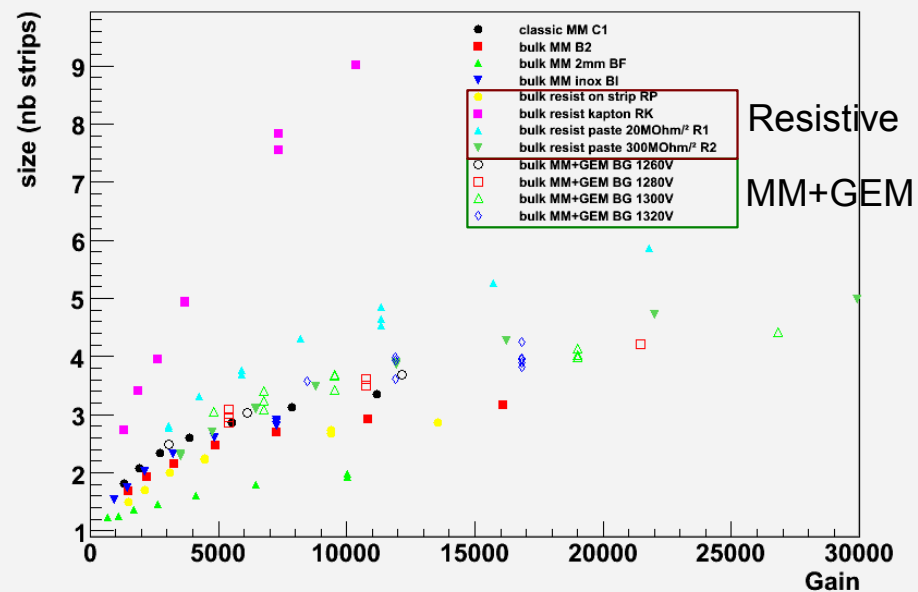
Prototypes efficiencies

Cluster sizes

Efficiencies vs gain



Cluster size vs gain



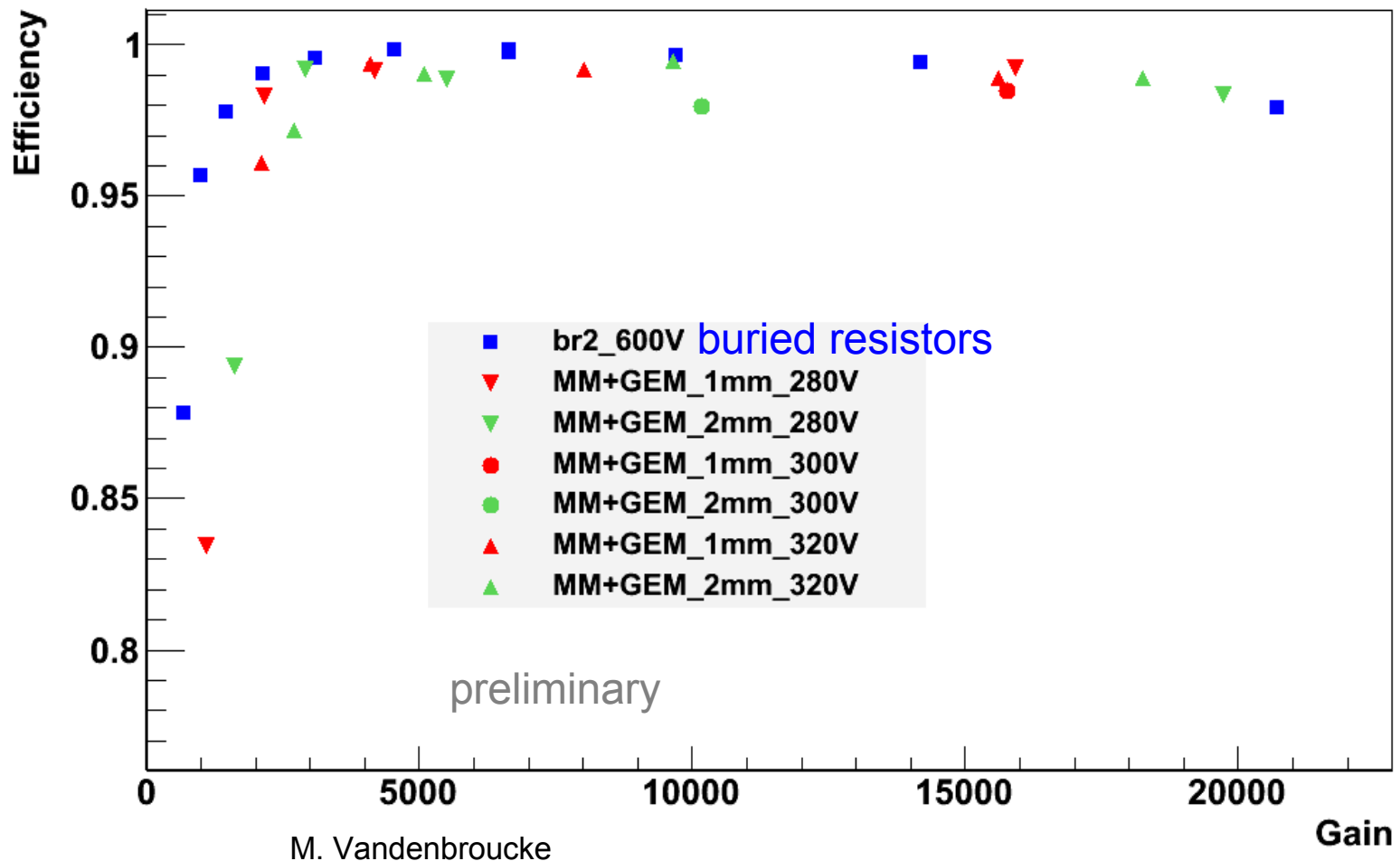
Efficiencies (2010 SPS tests)

Tests with muon+hadron beam (RD51 tests)

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Efficiencies vs Gain



M. Vandembroucke

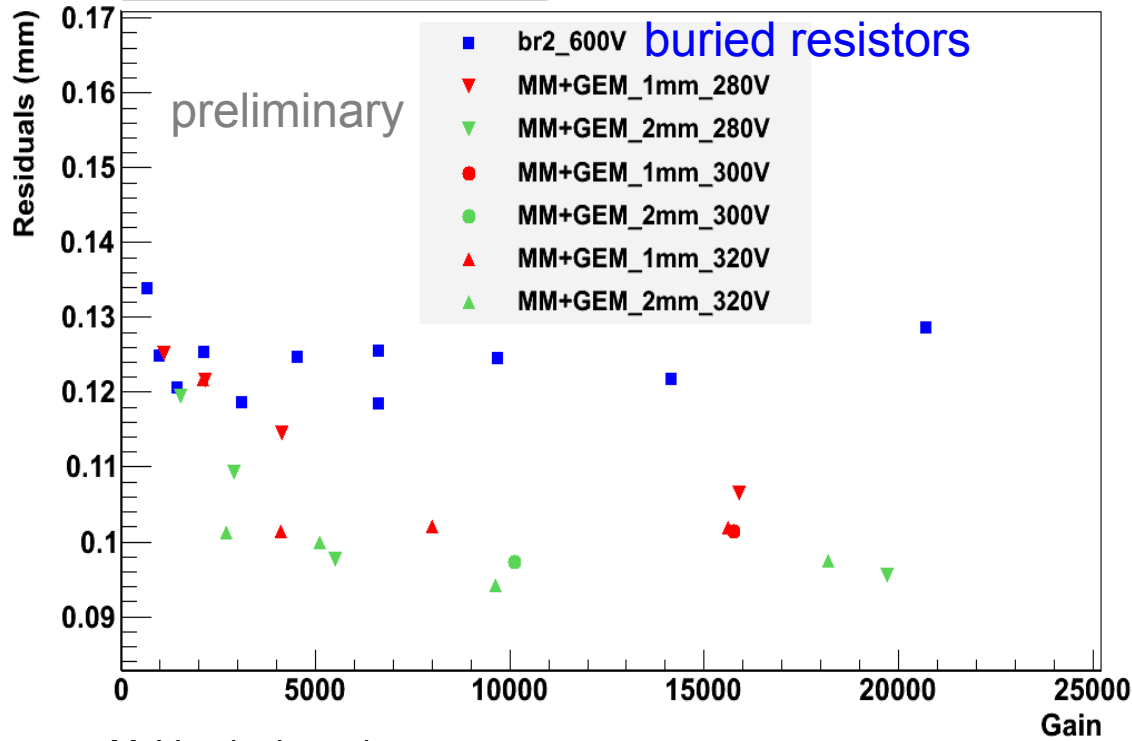
Residuals (2010 SPS tests)

Tests with muon+hadron beam (RD51 tests)

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Residuals vs gain



MM+GEM is a solution

- discharge rate decreased by factor $\gg 10$
- efficiencies and spatial resolution ok

Buried resistor promising solution, further studies needed

- spatial resolution
- gain at high flux
- production of large size detectors

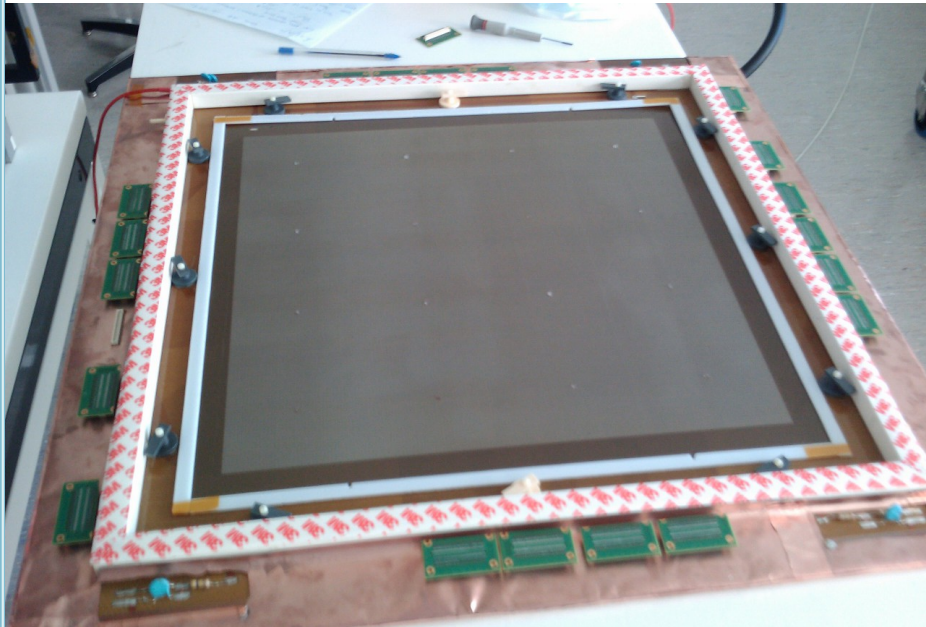
M. Vandenbroucke

Activités prévues en 2011

2 détecteurs MM+GEM pixel de grande taille

1 prototype installé à COMPASS

But: optimisation fonctionnement détecteur (HT) et électronique



1 prototype « résistances enterrées » pixel grande taille

En cours de développement au CERN, prévu pour l'automne 2011

Conclusions

Design de détecteurs MM de grande taille pixellisés en cours de validation

Dessin incluant 1280 pixels au centre du détecteur

Lecture par circuits APV25 validés, performances similaire à l'électronique utilisée sur les détecteurs actuels

Performances en faisceau en cours d'analyse

Réduction de l'impact des décharges

Excellents résultats de la solution avec feuille GEM additionnelle, à valider sur des détecteurs de grande taille

Pas de solution validée avec couche résistive

Mais résultats intéressants des prototypes « résistances enterrées », études à compléter

Prochaines étapes

2011: prototypes avec feuille GEM et avec résistances enterrées en test

2012: début de la production des nouveaux détecteurs

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